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2LE

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24

•	Members of the Texas Instruments <i>Widebus</i> ™ Family <i>EPIC</i> ™ (Enhanced-Performance Implanted	SN54AHC16373 WD PACKAGE SN74AHC16373 DGG, DGV, OR DL PACKAGE (TOP VIEW)
	CMOS) Process	
•	Operating Range 2-V to 5.5-V V <sub>CC</sub>	1Q1 <b>[</b> ] <sub>2</sub> 47 <b>[</b> ] 1D1
•	Distributed V <sub>CC</sub> and GND Pins Minimize	1Q2 🛛 <sub>3 46</sub> 🗋 1D2
	High-Speed Switching Noise	GND 4 45 GND
	Flow-Through Architecture Optimizes PCB	1Q3 🛛 5 44 🖸 1D3
	Layout	1Q4 [] 6 43 [] 1D4
	Latch-Up Performance Exceeds 250 mA Per	
	JESD 17	
•	ESD Protection Exceeds 2000 V Per	
	MIL-STD-883, Method 3015; Exceeds 200 V	GND [ <sub>10</sub> 39 ] GND 1Q7 [ <sub>11 38</sub> ] 1D7
	Using Machine Model (C = 200 pF, R = 0)	1Q7 [] <sub>11 38</sub> [] 1D7 1Q8 [] <sub>12 37</sub> [] 1D8
•	Package Options Include Plastic Shrink	2Q1 [ 13 36 ] 2D1
	Small-Outline (DL), Thin Shrink	2Q2 [ 14 35 ] 2D2
	Small-Outline (DGG), and Thin Very	GND [] 15 34 [] GND
	Small-Outline (DGV) Packages and 380-mil	2Q3 [ 16 33 ] 2D3
	Fine-Pitch Ceramic Flat (WD) Package	2Q4 [ 17 32 ] 2D4
	Using 25-mil Center-to-Center Spacings	$V_{CC}$ $\begin{bmatrix} 1\\18 & 31 \end{bmatrix}$ $V_{CC}$
ممم	winstie e	2Q5 [ <sub>19 30</sub> ] 2D5
aesc	ription	2Q6 🛛 <sub>20</sub> 29 🕽 2D6
	The 'AHC16373 devices are 16-bit transparent	GND <b>[</b> 21 28 ] GND
	D-type latches with 3-state outputs designed	2Q7 <b>[</b> 22 27 <b>]</b> 2D7
	specifically for driving highly capacitive or	2 <u>Q8</u> [] <sub>23</sub> 26 ] 2D8

D-type latches with 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels at the D inputs.

A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54AHC16373 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C. The SN74AHC16373 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C.



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	(each 8-bit latch)									
	INPUTS	OUTPUT								
OE	LE	Q								
L	Н	Н	Н							
L	Н	L	L							
L	L	Х	Q <sub>0</sub>							
Н	Х	Х	Z							

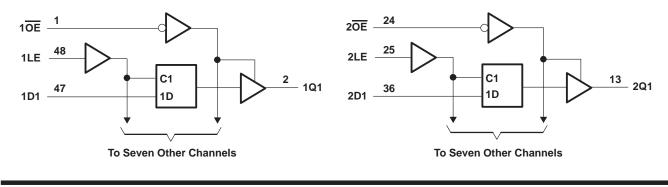
**FUNCTION TABLE** 

#### logic symbol<sup>†</sup>

			-	
1 <mark>OE</mark>	1	1EN		
1LE	48	СЗ		
	24			
2 <mark>0E</mark>	25	2EN		
2LE		C4		
	47		2	
1D1	46	3D 1 ⊽	3	1Q1
1D2	44		5	1Q2
1D3	43	-	6	1Q3
1D4	41		8	1Q4
1D5	40	-	9	1Q5
1D6	38	-	11	1Q6
1D7	37	-	12	1Q7
1D8		-		1Q8
2D1	36	4D 2 ⊽	13	2Q1
2D2	35	-	14	2Q2
2D3	33	-	16	2Q3
2D4	32		17	2Q4
2D5	30		19	2Q5
2D6	29		20	2Q6
2D7	27		22	2Q7
2D7 2D8	26		23	2Q7
200			1	200

<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### logic diagram (positive logic)





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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

DL package	$\begin{array}{c} -0.5 \mbox{ V to 7 V} \\ -0.5 \mbox{ V to V}_{CC} + 0.5 \mbox{ V} \\ -20 \mbox{ mA} \\ \pm 20 \mbox{ mA} \\ \pm 25 \mbox{ mA} \\ \pm 25 \mbox{ mA} \\ \pm 75 \mbox{ mA} \\ -70 \mbox{ °C/W} \\ -58 \mbox{ °C/W} \\ -63 \mbox{ °C/W} \end{array}$
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

#### recommended operating conditions (see Note 3)

			SN54AH	C16373	SN74AH0	216373	UNIT		
			MIN	MAX	MIN	MAX	UNIT		
Vcc	Supply voltage		2	5.5	2	5.5	V		
		$V_{CC} = 2 V$	1.5		1.5				
VIH	High-level input voltage	$V_{CC} = 3 V$	2.1		2.1		V		
		$V_{CC} = 5.5 V$	3.85		3.85				
		V <sub>CC</sub> = 2 V		0.5		0.5			
VIL	Low-level input voltage	V <sub>CC</sub> = 3 V		0.9		0.9	V		
	$V_{CC} = 5.5 V$			1.65		1.65			
VI	Input voltage		0	5.5	0	5.5	V		
Vo	Output voltage		0 <	Vcc	0	VCC	V		
		V <sub>CC</sub> = 2 V	Ś	-50		-50	μA		
ЮН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	20	-4		-4			
		$V_{CC} = 5 V \pm 0.5 V$	A.	-8		-8	mA		
		V <sub>CC</sub> = 2 V		50		50	μA		
IOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4			
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA		
	land the set the second second set	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100			
$\Delta t / \Delta v$	Input transition rise or fall rate	$V_{CC}$ = 5 V ± 0.5 V		20		20	ns/V		
Т <sub>А</sub>	Operating free-air temperature		-55	125	-40	85	°C		

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vee	Τ,	ן = 25°C	;	SN54AH0	C16373	SN74AHC	UNIT		
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
		2 V	1.9			1.9		1.9			
	I <sub>OH</sub> = -50 μA	3 V	2.9			2.9		2.9			
VOH		4.5 V	4.4			4.4		4.4		V	
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48			
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8	M:	3.8			
		2 V			0.1		0.1		0.1		
	I <sub>OL</sub> = 50 μA	3 V			0.1	, c	0.1		0.1	1	
V <sub>OL</sub>		4.5 V			0.1	6	0.1		0.1	V	
	I <sub>OL</sub> = 4 mA	3 V			0.36	$n_{O}$	0.5		0.44		
	I <sub>OL</sub> = 8 mA	4.5 V			0.36	bo No	0.5		0.44		
Ц	$V_{I} = V_{CC} \text{ or } GND$	0 V to 5.5 V			±0.1	Y	±1*		±1	μΑ	
loz	$V_{O} = V_{CC} \text{ or GND},$ $V_{I} = V_{IL} \text{ or } V_{IH}$	5.5 V			±0.25		±2.5		±2.5	μA	
ICC	$V_{I} = V_{CC} \text{ or } GND,  I_{O} = 0$	5.5 V			4		40		40	μΑ	
Ci	$V_I = V_{CC}$ or GND	5 V		2.5	10				10	pF	
Co	$V_{O} = V_{CC} \text{ or } GND$	5 V		4						pF	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0$  V.

# timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

		T <sub>A</sub> = 25°C		SN54AHC16373		SN74AHC16373		UNIT
		MIN	MAX	MIN	<b>МАХ</b>	MIN	MAX	UNIT
tw	Pulse duration, LE high	5		5	N.N	5		ns
t <sub>su</sub>	Setup time, data before LE $\downarrow$	4		4		4		ns
th	Hold time, data after LE $\downarrow$	1		<u> </u>		1		ns

# timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

		T <sub>A</sub> = 2	T <sub>A</sub> = 25°C		SN54AHC16373		16373	UNIT
		MIN	MAX	MIN	мах	MIN	MAX	UNIT
tw	Pulse duration, LE high	5		5	N.N	5		ns
t <sub>su</sub>	Setup time, data before LE $\downarrow$	4		4		4		ns
t <sub>h</sub>	Hold time, data after LE $\downarrow$	1		হ প		1		ns



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switching characteristics over recommended operating free-air temperature range,
$V_{CC}$ = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	Т	_= 25°C		SN54AHC	16373	SN74AHC	16373								
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT							
<sup>t</sup> PLH			0 15 5		7.3*	13*	1*	15*	1	15								
<sup>t</sup> PHL	D	Q	C <sub>L</sub> = 15 pF		7.3*	13*	1*	15*	1	15	ns							
<sup>t</sup> PLH	LE	Q	Ci = 15 pE		7*	13*	1*	15*	1	15	ns							
<sup>t</sup> PHL		Q	C <sub>L</sub> = 15 pF		7*	13*	1**	15*	1	15	115							
<sup>t</sup> PZH	OE	Q	CL = 15 pF		7.3*	13*	1*	15*	1	15	ns							
<sup>t</sup> PZL	ÛE	Q	0L = 15 pr		7.3*	13*	1*	15*	1	15	115							
<sup>t</sup> PHZ	OE	Q	C <sub>1</sub> = 15 pF		10*	14*	1*	16*	1	16	ns							
<sup>t</sup> PLZ	ÛE		~	<u> </u>	3	3			10*	14*	1*	<b>2</b> 16*	1	16				
<sup>t</sup> PLH	D	Q	C <sub>L</sub> = 50 pF		9.8	14	16	16	1	16	ns							
<sup>t</sup> PHL	D	Q	Š	<u> </u>	<u> </u>	<u> </u>	4	4	×			9.8	14	6	16	1	16	110
<sup>t</sup> PLH	LE	Q	C <sub>L</sub> = 50 pF		9.5	14.5	A 1	16.5	1	16.5	ns							
<sup>t</sup> PHL		~	0L = 00 pl		9.5	14.5	1	16.5	1	16.5	115							
<sup>t</sup> PZH	OE	Q	$C_{1} = 50  pF$		9.3	14.9	1	16	1	16	ns							
tPZL	02	~	0L = 00 pl		8	14.9	1	16	1	16	110							
<sup>t</sup> PHZ	OE	Q	C <sub>1</sub> = 50 pF		10.4	15.5	1	17	1	17	ns							
<sup>t</sup> PLZ			Ğ	3		ο <sup>Γ</sup> = 20 μι		11.6	15.5	1	17	1	17					
<sup>t</sup> sk(o)			C <sub>L</sub> = 50 pF			1.5**				1.5	ns							

\* On products compliant to MIL-PRF-38535, this parameter is not production tested. \*\* On products compliant to MIL-PRF-38535, this parameter does not apply.

switching characteristics over recommended operating free-air temperature range,	
$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ (unless otherwise noted) (see Figure 1)	

DADAMETED	FROM	то	LOAD	DAD $T_A = 25^{\circ}C$		SN54AHC	16373	SN74AHC	16373	LINUT				
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT			
<sup>t</sup> PLH	D	Q	Ci - 15 pE		5*	8.2*	1*	9.5*	1	9.5	ns			
<sup>t</sup> PHL		Q	C <sub>L</sub> = 15 pF		5*	8.2*	1*	9.5*	1	9.5	115			
<sup>t</sup> PLH		Q	C <sub>L</sub> = 15 pF		4.9*	8.5*	1*	9.5*	1	9.5	ns			
<sup>t</sup> PHL	LE	ý	CL = 15 pr		4.9*	8.5*	1*	9.5*	1	9.5	115			
<sup>t</sup> PZH	OE	Q	C <sub>I</sub> = 15 pF		5.5*	9.1*	1*	10*	1	10	ns			
<sup>t</sup> PZL	ÛE	ý	0 <u>[</u> = 15 pi		5.5*	9.1*	1*	10*	1	10	115			
<sup>t</sup> PHZ		0	C <sub>L</sub> = 15 pF		5*	9.5*	1*	10*	1	10	ns			
<sup>t</sup> PLZ				5*	9.5*	1* 🗸	10*	1	10	113				
<sup>t</sup> PLH	D	Q	C <sub>I</sub> = 50 pF		6.5	9.2	10	10.5	1	10.5	ns			
<sup>t</sup> PHL	D	Q	Q	Q	0L = 30 pr		6.5	9.2	20	10.5	1	10.5	115	
<sup>t</sup> PLH	LE	Q	C <sub>1</sub> = 50 pF		6.4	9.5	1 42	10.5	1	10.5	ns			
<sup>t</sup> PHL	LL	ý	0L = 30 pi		6.4	9.5	1	10.5	1	10.5	115			
<sup>t</sup> PZH	OE	Q	C <sub>L</sub> = 50 pF		6	10.1	1	11.5	1	11.5	ns			
<sup>t</sup> PZL	OE	ý	0L = 30 pi		6	10.1	1	11.5	1	11.5	115			
<sup>t</sup> PHZ	OE	Q	C <sub>I</sub> = 50 pF		6.5	10.5	1	11.5	1	11.5	ns			
<sup>t</sup> PLZ	UE	L L	ν Υ		ý			7.5	10.5	1	11.5	1	11.5	115
<sup>t</sup> sk(o)			CL = 50 pF			1**				1	ns			

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

\*\* On products compliant to MIL-PRF-38535, this parameter does not apply.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.



# SN54AHC16373, SN74AHC16373 16-BIT TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS SCLS329G – MARCH 1996 – REVISED JANUARY 2000

### noise characteristics, V\_{CC} = 5 V, C\_L = 50 pF, T\_A = 25^{\circ}C (see Note 4)

DADAMETED	SN74	UNIT		
FARAIVIETER	MIN	TYP	MAX	UNIT
Quiet output, maximum dynamic V <sub>OL</sub>		0.34	0.8	V
Quiet output, minimum dynamic V <sub>OL</sub>		-0.1	-0.8	V
Quiet output, minimum dynamic V <sub>OH</sub>		4.6		V
High-level dynamic input voltage	3.5			V
Low-level dynamic input voltage			1.5	V
	Quiet output, minimum dynamic V <sub>OL</sub> Quiet output, minimum dynamic V <sub>OH</sub> High-level dynamic input voltage	PARAMETER       MIN         Quiet output, maximum dynamic V <sub>OL</sub> Quiet output, minimum dynamic V <sub>OL</sub> Quiet output, minimum dynamic V <sub>OH</sub> High-level dynamic input voltage       3.5	PARAMETER     MIN     TYP       Quiet output, maximum dynamic V <sub>OL</sub> 0.34       Quiet output, minimum dynamic V <sub>OL</sub> -0.1       Quiet output, minimum dynamic V <sub>OH</sub> 4.6       High-level dynamic input voltage     3.5	MINTYPMAXQuiet output, maximum dynamic VOL0.340.8Quiet output, minimum dynamic VOL-0.1-0.8Quiet output, minimum dynamic VOH4.6-0.1High-level dynamic input voltage3.5-0.1

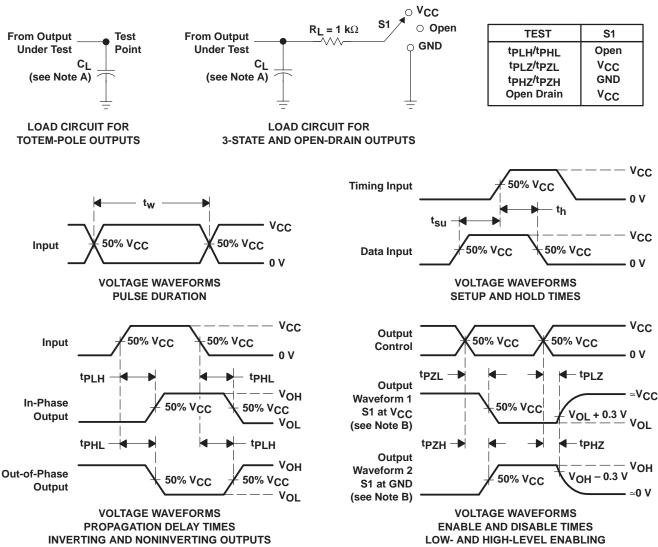
NOTE 4: Characteristics are for surface-mount packages only.

#### operating characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	No load, f = 1 MHz	21	рF



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74AHC16373DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC16373	Samples
SN74AHC16373DGVR	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HE373	Samples
SN74AHC16373DL	LIFEBUY	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC16373	
SN74AHC16373DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC16373	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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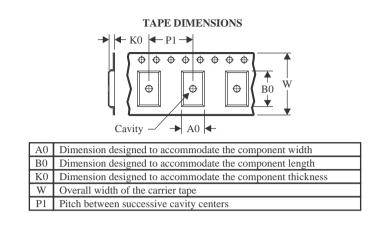


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STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC16373DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74AHC16373DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74AHC16373DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1



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### PACKAGE MATERIALS INFORMATION

3-Jun-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC16373DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74AHC16373DGVR	TVSOP	DGV	48	2000	356.0	356.0	35.0
SN74AHC16373DLR	SSOP	DL	48	1000	367.0	367.0	55.0

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3-Jun-2022

#### TUBE



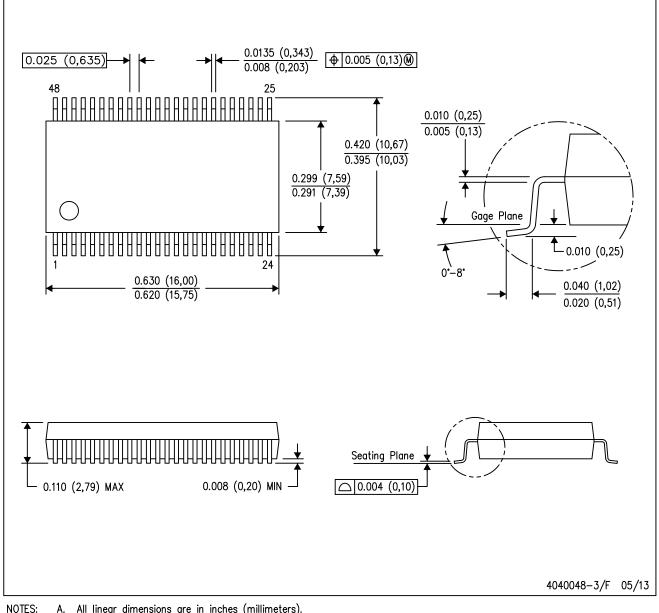
#### - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74AHC16373DL	DL	SSOP	48	25	473.7	14.24	5110	7.87

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.



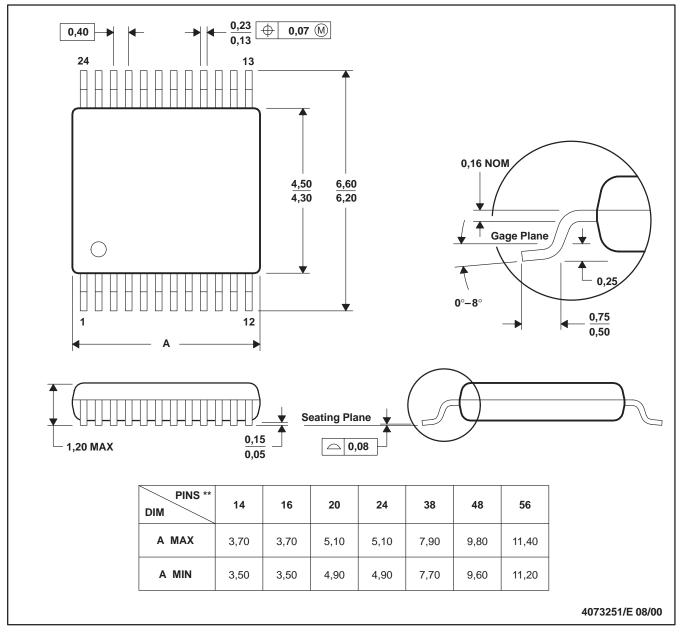
### **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

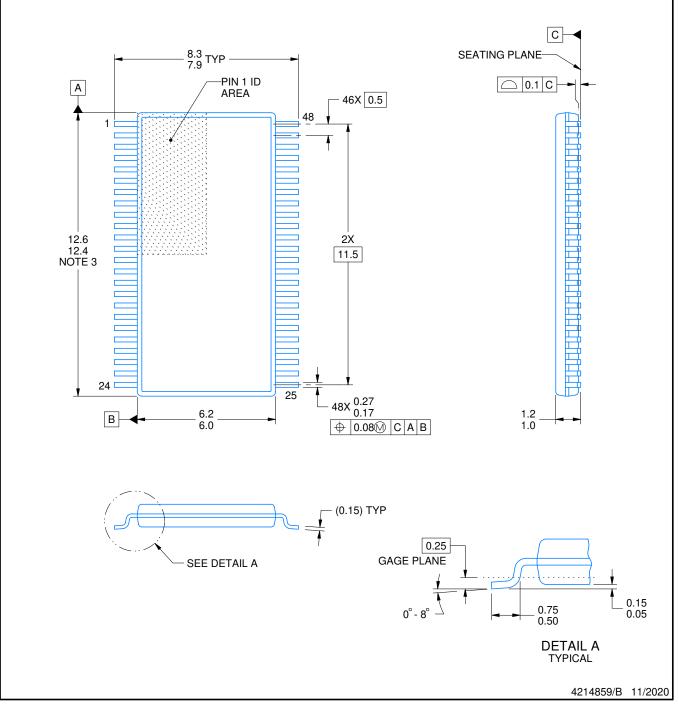
14/16/20/56 Pins – MO-194



### **PACKAGE OUTLINE**

#### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  This drawing is subject to change without notice.
  This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



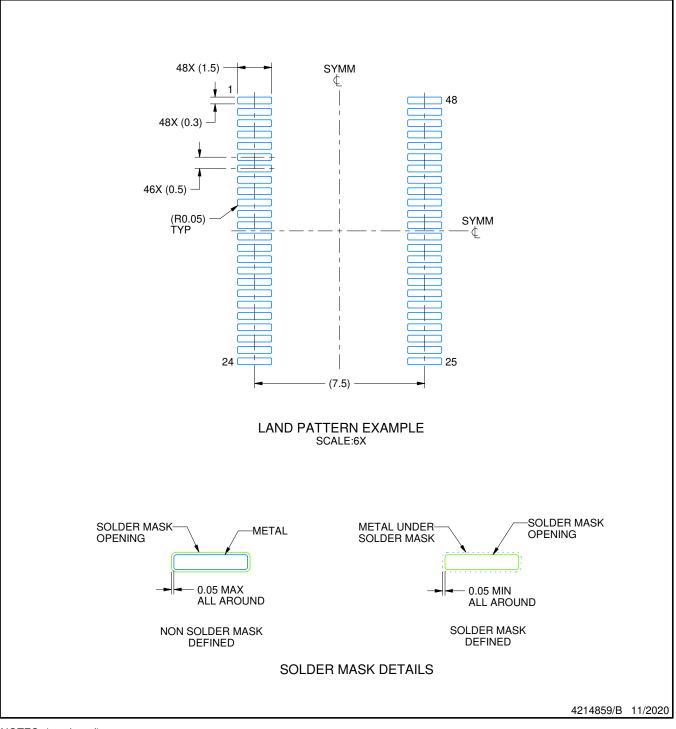
### **DGG0048A**

### DGG0048A

## **EXAMPLE BOARD LAYOUT**

#### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

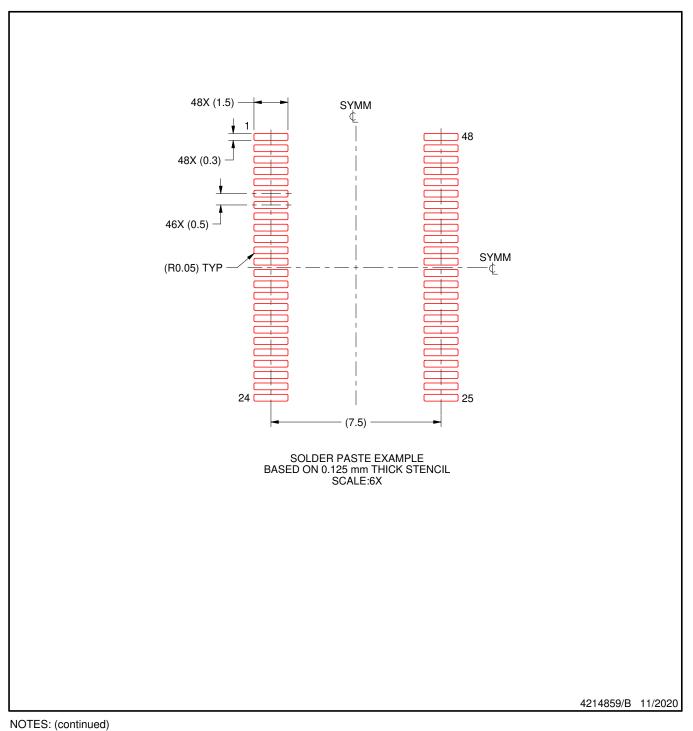


### DGG0048A

## **EXAMPLE STENCIL DESIGN**

#### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



#### **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### DGG (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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